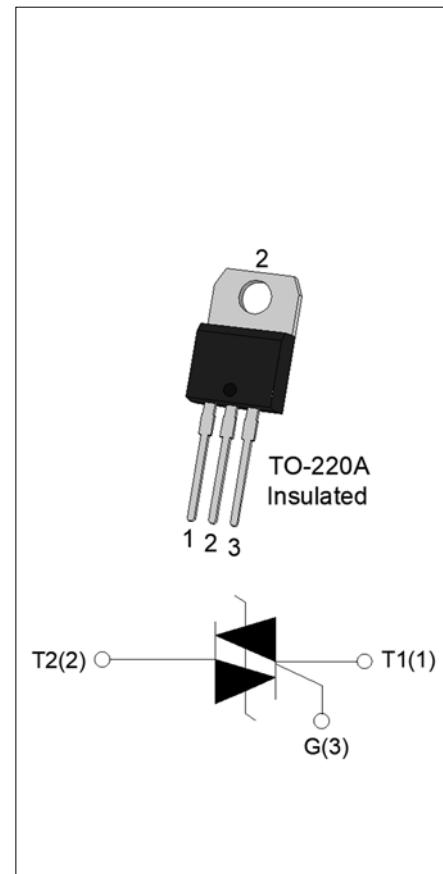


**DESCRIPTION:**

The ACJT08A-800CW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. The ACJT08A-800CW embeds a TVS structure to absorb the inductive turn-off energy such as those described in the IEC 61000-4-5 standards. By using an internal ceramic pad, ACJT08A-800CW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.

**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
$V_{DRM} / V_{RRM}$	800	V
$I_{GT\text{ I/II/III}}$	35/35/35	mA

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-125	°C
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	800	V
RMS on-state current ( $T_c \leqslant 97^\circ\text{C}$ )	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	80	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		88	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	32	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	$dI/dt$	100	$\text{A}/\mu\text{s}$
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{GM}$	4	A

Average gate power dissipation ( $T_j=125^\circ\text{C}$ )	$P_{G(AV)}$	0.5	W
Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25^\circ\text{C}$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	2.75	kV

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D = 12\text{V}$ $R_L = 33\Omega$	I - II - III	MAX.	35	mA
$V_{GT}$		I - II - III	MAX.	1	V
$V_{GD}$	$V_D = V_{DRM}$ $T_j = 125^\circ\text{C}$ $R_L = 3.3\text{K}\Omega$	I - II - III	MIN.	0.2	V
$I_L$	$I_G = 1.2I_{GT}$	I - III	MAX.	35	mA
		II		55	
$I_H$	$I_T = 100\text{mA}$	MAX.	30	mA	
$dV/dt$	$V_D = 540\text{V}$ Gate Open $T_j = 125^\circ\text{C}$	MIN.	2600	V/ $\mu\text{s}$	
$(dI/dt)c$	$(dV/dt)c = 10\text{V}/\mu\text{s}$ , $T_j = 125^\circ\text{C}$	MIN.	10	A/ms	
$t_{on}$	$I_G = 40\text{mA}$ $I_A = 200\text{mA}$ $I_R = 20\text{mA}$ $T_j = 25^\circ\text{C}$	TYP.	3	$\mu\text{s}$	
$t_{off}$			30		
$V_{CL}$	$I_{CL} = 0.1\text{mA}$ $t_p = 1\text{ms}$	MIN.	850	V	

**STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_{TM} = 10\text{A}$	$t_p = 380\mu\text{s}$	1.45	V
$V_{TO}$	Threshold voltage	$T_j = 125^\circ\text{C}$	0.78	V
$R_D$	Dynamic resistance	$T_j = 125^\circ\text{C}$	48	$\text{m}\Omega$
$I_{DRM}$	$V_D = V_{DRM}$ $V_R = V_{RRM}$	$T_j = 25^\circ\text{C}$	5	$\mu\text{A}$
$I_{RRM}$		$T_j = 125^\circ\text{C}$	0.5	mA

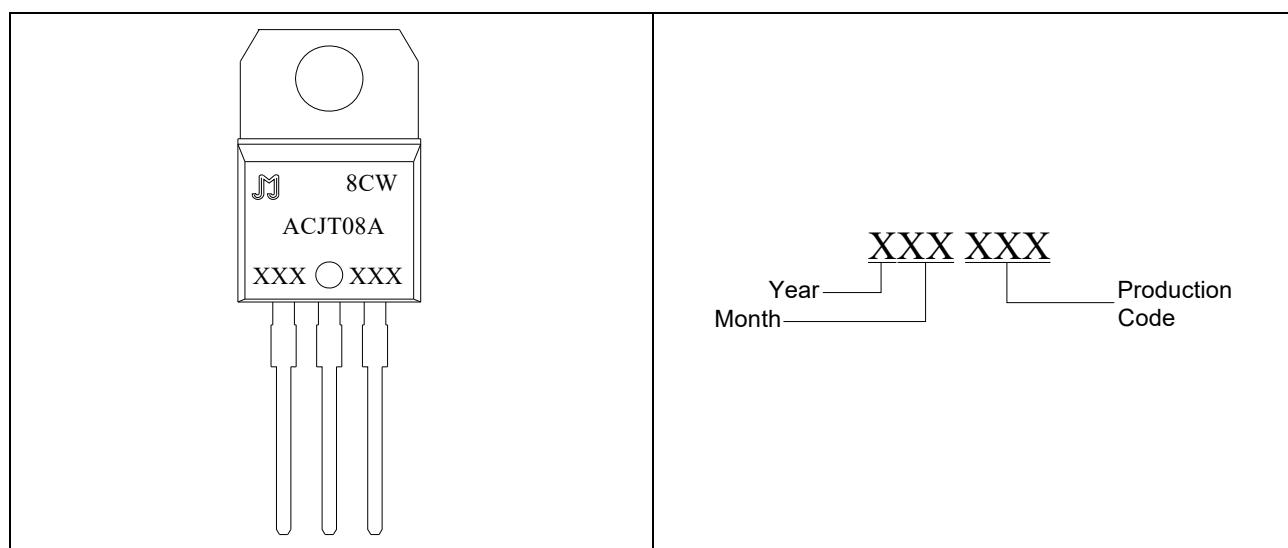
**THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	2.5	$^\circ\text{C/W}$
$R_{th(j-a)}$	junction to ambient (AC)	60	$^\circ\text{C/W}$

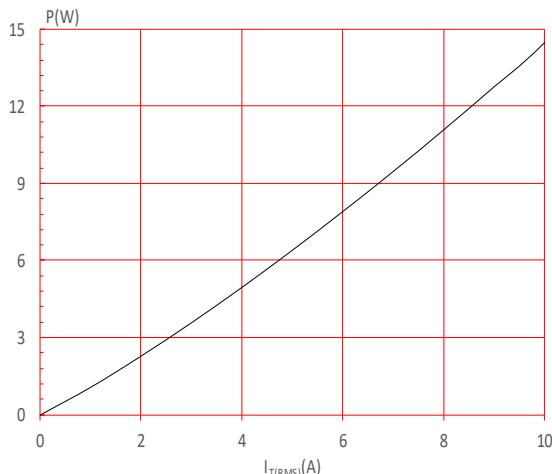
## ORDERING INFORMATION

AC	J	T	08	A	-800	CW
<u>AC switch</u>						
<u>JieJie Microelectronics Co., Ltd.</u>						
		<u>Triacs</u>				
			<u><math>I_{T(RMS)}:8A</math></u>			
				<u>A:TO-220A(Ins)</u>		
					<u>800:V<sub>DRM</sub> / V<sub>RRM</sub> ≥ 800V</u>	
						<u>CW: I<sub>GT1-3</sub> ≤ 35mA</u>

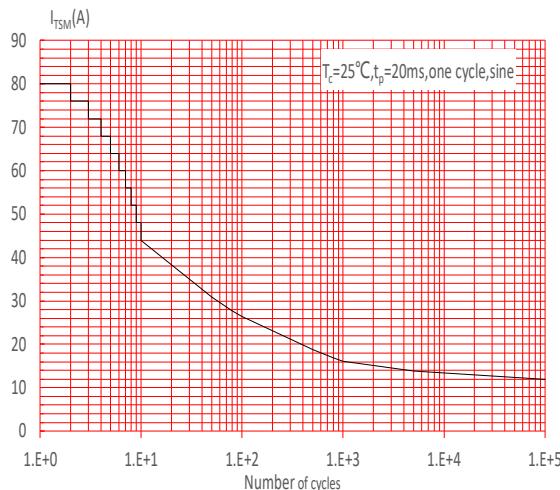
## MARKING



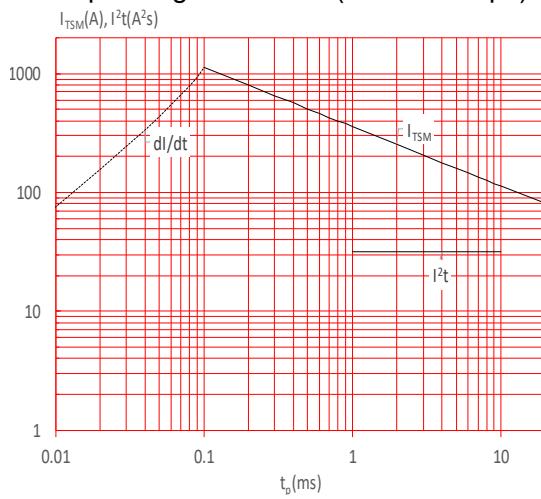
**FIG.1** Maximum power dissipation versus RMS on-state current



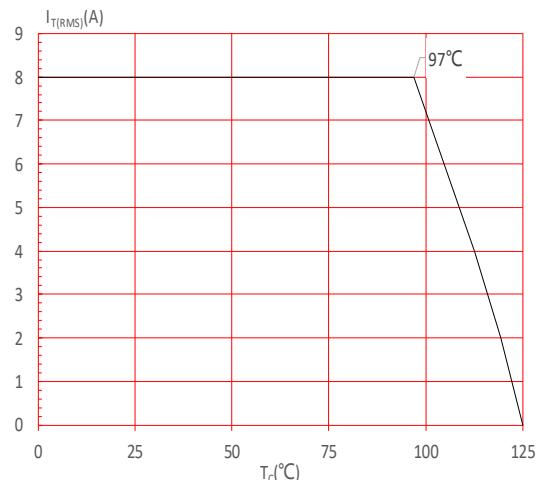
**FIG.3:** Surge peak on-state current versus number of cycles



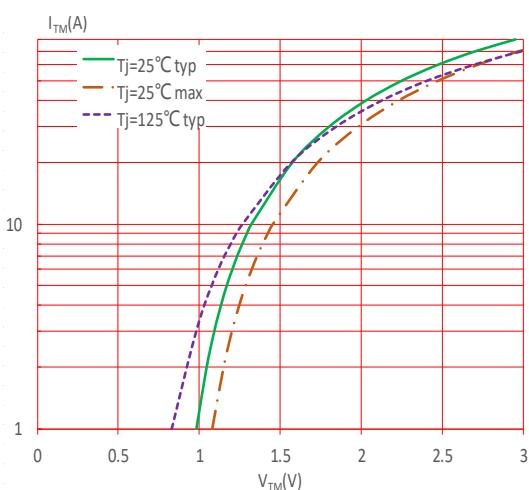
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 100\text{A}/\mu\text{s}$ )



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

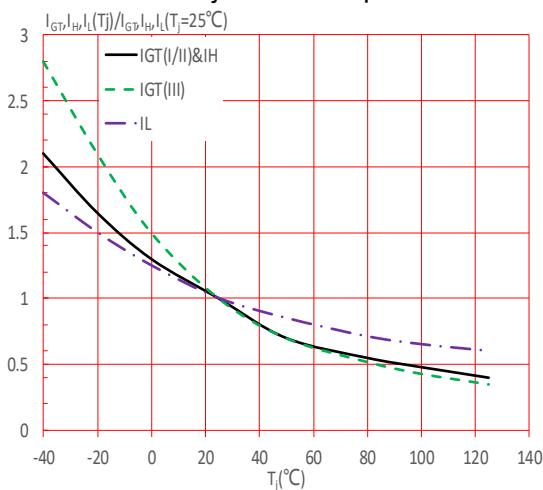
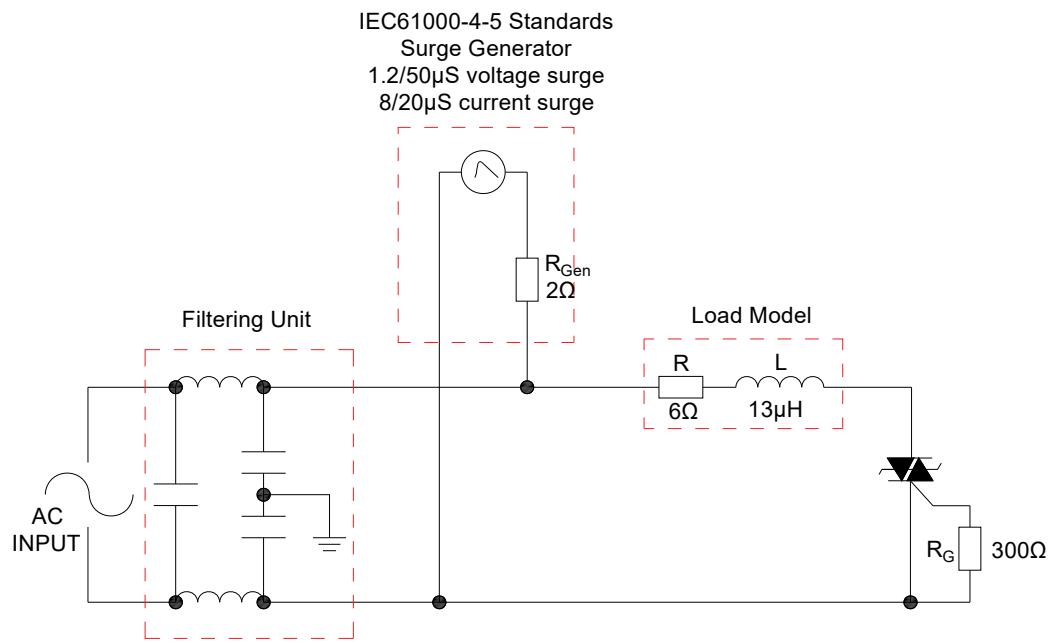


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



## SHAPING AND SOLDERING PARAMETERS

Refer to 《Instructions for installation of plastic-sealed in-line power devices》 released by JieJie

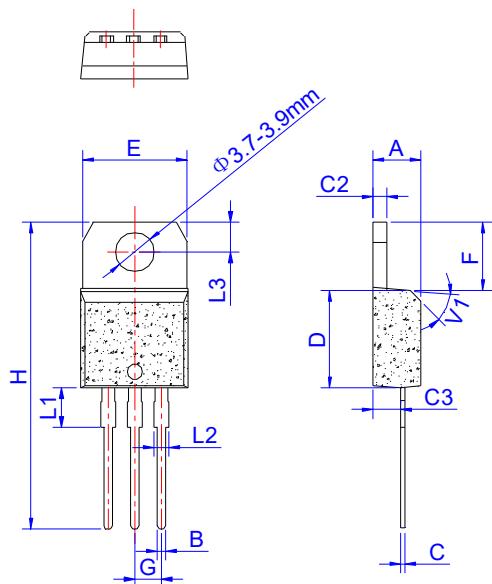
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
<b>ACJT08A-800CW</b>	<b>800</b>	<b>35</b>	<b>TO-220A(Ins)</b>	<b>50</b>	<b>Tube</b>

**Document Revision History**

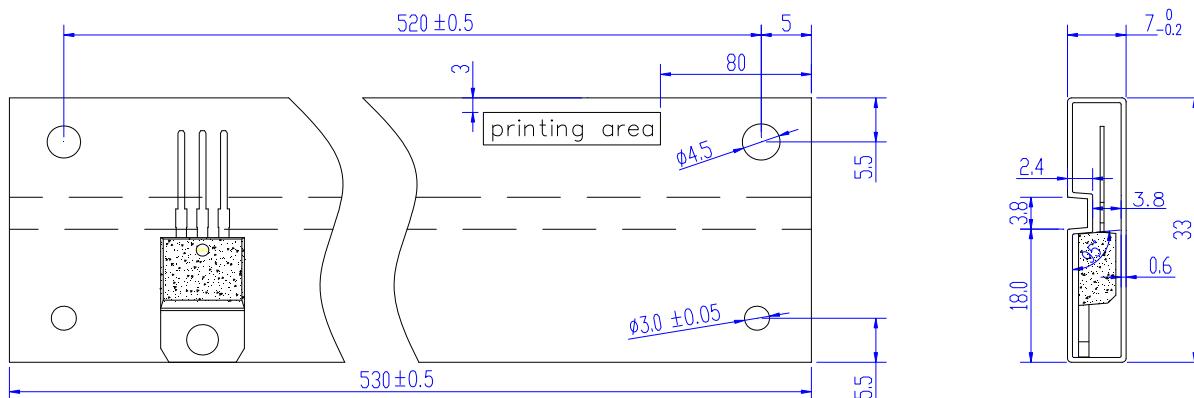
Date	Revision	Changes
Apr.13, 2023	A.1.0	Last updated

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.25		6.85	0.246		0.270
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.45		4.05	0.136		0.159
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220A	TUBE	50	1,000	5,000

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